

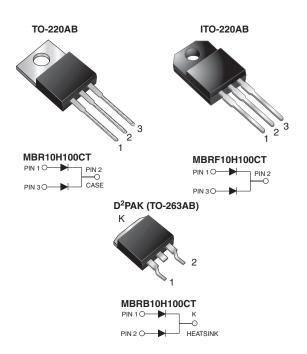
# MBR10H100CT, MBRF10H100CT, MBRB10H100CT

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Vishay General Semiconductor

# **Dual Common Cathode High Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



#### **DESIGN SUPPORT TOOLS**

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PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5 A				
$V_{RRM}$	100 V				
I <sub>FSM</sub>	150 A				
$V_{F}$	0.61 V				
I <sub>R</sub>	3.5 μA				
T <sub>J</sub> max.	175 °C				
Package	TO-220AC, ITO-220AC, D <sup>2</sup> PAK (TO-263AB)				
Circuit configurations	Common cathode				

#### **FEATURES**

Power pack





- Low power loss, high efficiency
- Low forward voltage drop
- Low looks as surrent
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### **TYPICAL APPLICATIONS**

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER			MBR10H100CT	UNIT		
Maximum repetitive peak reverse voltage		$V_{RRM}$	100			
Working peak reverse voltage		$V_{RWM}$	100	V		
Maximum DC blocking voltage	laximum DC blocking voltage		100			
Maximum average forward rectified current	total device	1	10	A		
at T <sub>C</sub> = 105 °C	per diode	I <sub>F(AV)</sub>	5.0			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			150	A		
Peak repetitive reverse current per diode at $t_p = 2.0 \mu s$ , 1 kHz			0.5			
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs		
Operating junction and storage temperature range			-65 to +175	°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		$V_{AC}$	1500	V		



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 5 A	T <sub>J</sub> = 25 °C	0.76	V	
		I <sub>F</sub> = 5 A	T <sub>J</sub> = 125 °C	0.61		
		I <sub>F</sub> = 10 A	T <sub>J</sub> = 25 °C	0.85		
		I <sub>F</sub> = 10 A	T <sub>J</sub> = 125 °C	0.71		
Maximum reverse current per diode	I <sub>R</sub> <sup>(1)</sup>	Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	3.5	μA	
iviaximum reverse current per diode			T <sub>J</sub> = 100 °C	4.5	mA	

#### **Notes**

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ heta JC}$	2.2	5.2	2.2	°C/W

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR10H100CT-E3/45	1.85	45	50/tube	Tube	
ITO-220AB	MBRF10H100CT-E3/45	1.79	45	50/tube	Tube	
TO-263AB	MBRB10H100CT-E3/45	1.35	45	50/tube	Tube	
TO-263AB	MBRB10H100CT-E3/81	1.35	81	800/reel	Tape and reel	

## **RATINGS AND CHARACTERISTICS CURVES** ( $T_C = 25$ °C unless otherwise noted)

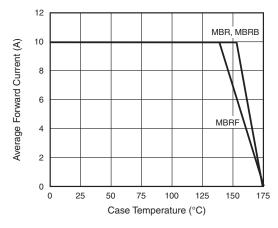


Fig. 1 - Forward Current Derating Curve Per Diode

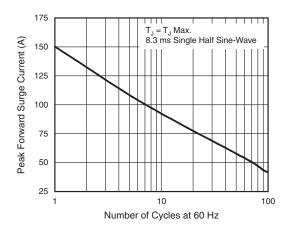


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

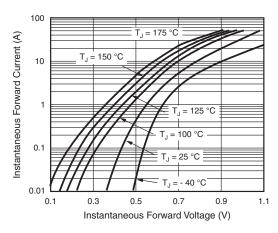


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

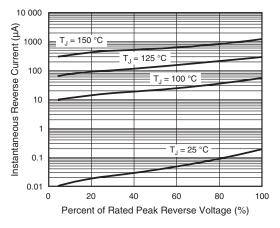


Fig. 4 - Typical Reverse Characteristics Per Diode

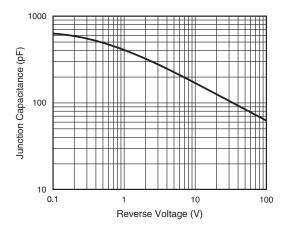


Fig. 5 - Typical Junction Capacitance Per Diode

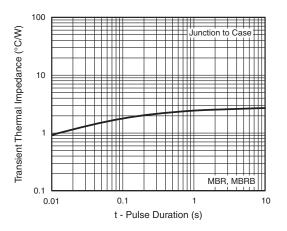


Fig. 6 - Typical Transient Thermal Impedance Per Diode

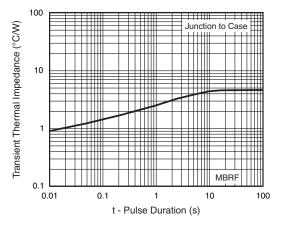


Fig. 7 - Typical Transient Thermal Impedance Per Diode

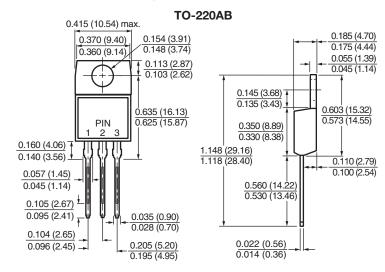


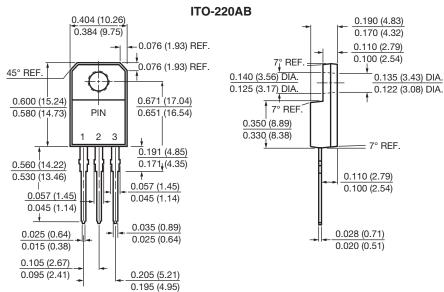


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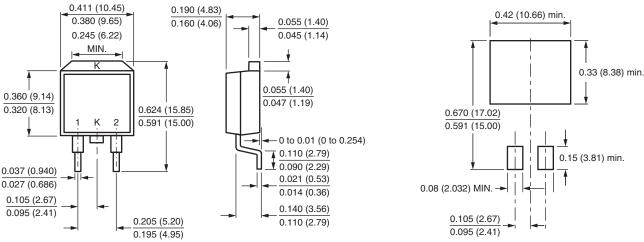
## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters





#### D<sup>2</sup>PAK (TO-263AB)

# Mounting Pad Layout





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MBRB10H100CT-E3/81 MBRB10H90CT/81 MBRB10H90CT-E3/31 MBRB10H90CT-E3/81 MBRF10H100CT-E3/45

MBRF10H90CT-E3/45 MBR10H100CTHE3/45 MBRB10H100CTHE3/45 MBRB10H100CTHE3/81 MBRB10H90CT/31

MBRF10H100CTHE3/45 MBRB10H100CT-E3/45 MBRB10H100CT-M3/4W MBRB10100CT-M3/8W